

View Online at <https://aerobasegroup.com/nsn/5961-01-106-4654>

Inclosure Material:

Plastic

Overall Length:

0.785 inches

Overall Height:

0.200 inches

Overall Width:

0.375 inches

Component Name And Quantity:

4 transistor

Mounting Method:

Press fit

Features Provided:

Burn in and hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, instantaneous all transistor

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

1900.0 milliwatts small-signal input power, common-collector preset all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

12 ribbon

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fig:

A110a0